## 40 V, 2.0 A, Low V<sub>CE(sat)</sub> NPN Transistor

ON Semiconductor's e²PowerEdge family of low  $V_{CE(sat)}$  transistors are miniature surface mount devices featuring ultra low saturation voltage ( $V_{CE(sat)}$ ) and high current gain capability. These are designed for use in low voltage, high speed switching applications where affordable efficient energy control is important.

Typical applications are DC-DC converters and power management in portable and battery powered products such as cellular and cordless phones, PDAs, computers, printers, digital cameras and MP3 players. Other applications are low voltage motor controls in mass storage products such as disc drives and tape drives. In the automotive industry they can be used in air bag deployment and in the instrument cluster. The high current gain allows e<sup>2</sup>PowerEdge devices to be driven directly from PMU's control outputs, and the Linear Gain (Beta) makes them ideal components in analog amplifiers.

#### **Features**

- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant\*



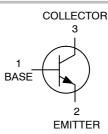
#### ON Semiconductor®

http://onsemi.com

# 40 VOLTS, 2.0 AMPS NPN LOW $V_{CE(sat)}$ TRANSISTOR EQUIVALENT $R_{DS(on)}$ 44 m $\Omega$



SOT-23 (TO-236) CASE 318 STYLE 6



#### **MARKING DIAGRAM**



VB = Specific Device Code\*

M = Date Code\*

■ = Pb-Free Package

(Note: Microdot may be in either location)

\*Specific Device Code, Date Code or overbar orientation and/or location may vary depending upon manufacturing location. This is a representation only and actual devices may not match this drawing exactly.

#### ORDERING INFORMATION

Device	Package	Shipping <sup>†</sup>
NSS40201LT1G	SOT-23 (Pb-Free)	3,000 / Tape & Reel
NSV40201LT1G	SOT-23 (Pb-Free)	3,000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

<sup>\*</sup>For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

### **MAXIMUM RATINGS** $(T_A = 25^{\circ}C)$

Rating	Symbol	Max	Unit
Collector-Emitter Voltage	V <sub>CEO</sub>	40	Vdc
Collector-Base Voltage	V <sub>CBO</sub>	40	Vdc
Emitter-Base Voltage	V <sub>EBO</sub>	6.0	Vdc
Collector Current - Continuous	I <sub>C</sub>	2.0	Α
Collector Current - Peak	I <sub>CM</sub>	6.0	Α
Electrostatic Discharge	ESD	HBM Class 3B MM Class C	

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation  T <sub>A</sub> = 25°C  Derate above 25°C	P <sub>D</sub> (Note 1)	460 3.7	mW mW/°C
Thermal Resistance, Junction-to-Ambient	R <sub>θJA</sub> (Note 1)	270	°C/W
Total Device Dissipation  T <sub>A</sub> = 25°C  Derate above 25°C	P <sub>D</sub> (Note 2)	540 4.3	mW mW/°C
Thermal Resistance, Junction-to-Ambient	R <sub>θJA</sub> (Note 2)	230	°C/W
Junction and Storage Temperature Range	$T_J,T_stg$	-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. FR-4 @ 100 mm<sup>2</sup>, 1 oz. copper traces.

2. FR-4 @ 500 mm<sup>2</sup>, 1 oz. copper traces.

## **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS	1			,	,
Collector – Emitter Breakdown Voltage ( $I_C = 10 \text{ mAdc}, I_B = 0$ )	V <sub>(BR)CEO</sub>	40	_	_	Vdc
Collector – Base Breakdown Voltage ( $I_C = 0.1 \text{ mAdc}, I_E = 0$ )	V <sub>(BR)CBO</sub>	40	-	-	Vdc
Emitter – Base Breakdown Voltage ( $I_E = 0.1 \text{ mAdc}, I_C = 0$ )	V <sub>(BR)EBO</sub>	6.0	-	-	Vdc
Collector Cutoff Current (V <sub>CB</sub> = 40 Vdc, I <sub>E</sub> = 0)	I <sub>CBO</sub>	-	-	0.1	μAdc
Emitter Cutoff Current (V <sub>EB</sub> = 6.0 Vdc)	I <sub>EBO</sub>	-	-	0.1	μAdc
ON CHARACTERISTICS					
DC Current Gain (Note 3) ( $I_C = 10 \text{ mA}, V_{CE} = 2.0 \text{ V}$ ) ( $I_C = 500 \text{ mA}, V_{CE} = 2.0 \text{ V}$ ) ( $I_C = 1.0 \text{ A}, V_{CE} = 2.0 \text{ V}$ ) ( $I_C = 2.0 \text{ A}, V_{CE} = 2.0 \text{ V}$ )	h <sub>FE</sub>	200 200 180 180	- 370 - -	- - - -	
Collector – Emitter Saturation Voltage (Note 3) ( $I_C = 0.1 \text{ A}, I_B = 0.010 \text{ A}$ ) ( $I_C = 1.0 \text{ A}, I_B = 0.100 \text{ A}$ ) ( $I_C = 1.0 \text{ A}, I_B = 0.010 \text{ A}$ ) ( $I_C = 2.0 \text{ A}, I_B = 0.200 \text{ A}$ )	V <sub>CE(sat)</sub>	- - - -	0.006 0.044 0.085 0.082	0.011 0.060 0.115 0.115	V
Base – Emitter Saturation Voltage (Note 3) $(I_C = 1.0 \text{ A}, I_B = 10 \text{ mA})$	V <sub>BE(sat)</sub>	-	0.760	0.900	V
Base – Emitter Turn-on Voltage (Note 3) (I <sub>C</sub> = 1.0 A, V <sub>CE</sub> = 2.0 V)	V <sub>BE(on)</sub>	-	0.760	0.900	V
Cutoff Frequency (I <sub>C</sub> = 100 mA, V <sub>CE</sub> = 5.0 V, f = 100 MHz)	f <sub>T</sub>	150	-	-	MHz
Input Capacitance (V <sub>EB</sub> = 0.5 V, f = 1.0 MHz)	Cibo	-	-	450	pF
Output Capacitance (V <sub>CB</sub> = 3.0 V, f = 1.0 MHz)	Cobo	-	-	45	pF
SWITCHING CHARACTERISTICS					
Delay (V <sub>CC</sub> = 30 V, I <sub>C</sub> = 750 mA, I <sub>B1</sub> = 15 mA)	t <sub>d</sub>	-	_	100	ns
Rise ( $V_{CC}$ = 30 V, $I_{C}$ = 750 mA, $I_{B1}$ = 15 mA)	t <sub>r</sub>	_	_	100	ns
Storage ( $V_{CC} = 30 \text{ V}, I_{C} = 750 \text{ mA}, I_{B1} = 15 \text{ mA}$ )	t <sub>s</sub>	_	_	750	ns
Fall ( $V_{CC} = 30 \text{ V}, I_C = 750 \text{ mA}, I_{B1} = 15 \text{ mA}$ )	t <sub>f</sub>	_	-	110	ns

<sup>3.</sup> Pulsed Condition: Pulse Width = 300 msec, Duty Cycle  $\leq$  2%.

#### **TYPICAL CHARACTERISTICS**

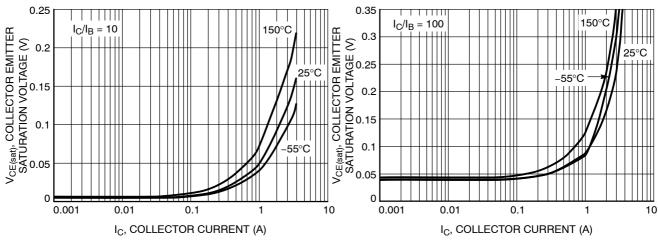


Figure 1. Collector Emitter Saturation Voltage vs. Collector Current

Figure 2. Collector Emitter Saturation Voltage vs. Collector Current

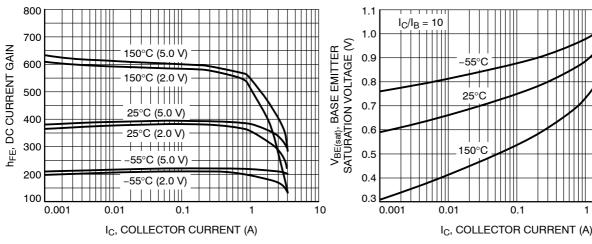


Figure 3. DC Current Gain vs. Collector Current

Figure 4. Base Emitter Saturation Voltage vs.
Collector Current

10

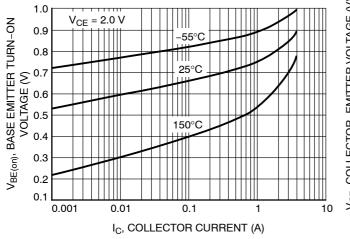


Figure 5. Base Emitter Turn-On Voltage vs. Collector Current

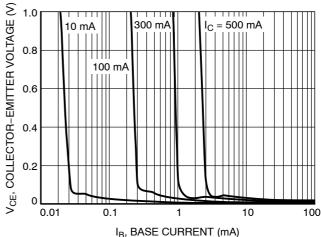


Figure 6. Saturation Region

#### **TYPICAL CHARACTERISTICS**

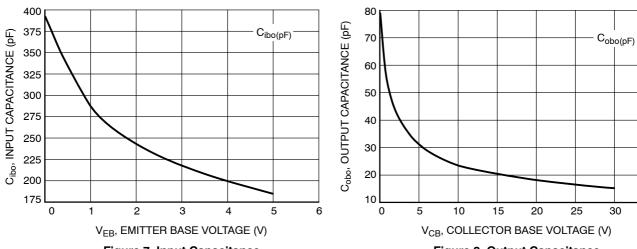


Figure 7. Input Capacitance

Figure 8. Output Capacitance

35

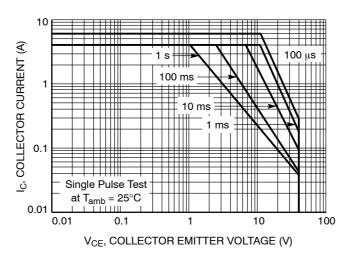
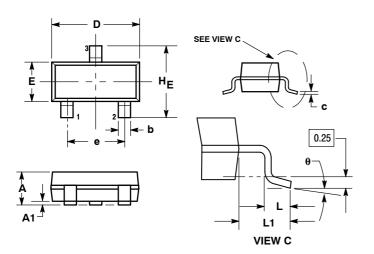


Figure 9. Safe Operating Area

#### PACKAGE DIMENSIONS

#### SOT-23 (TO-236) CASE 318-08 **ISSUE AP**



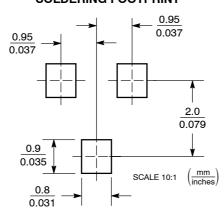
- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: INCH.
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
  DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH,
- PROTRUSIONS, OR GATE BURRS.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.89	1.00	1.11	0.035	0.040	0.044
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.37	0.44	0.50	0.015	0.018	0.020
С	0.09	0.13	0.18	0.003	0.005	0.007
D	2.80	2.90	3.04	0.110	0.114	0.120
E	1.20	1.30	1.40	0.047	0.051	0.055
е	1.78	1.90	2.04	0.070	0.075	0.081
L	0.10	0.20	0.30	0.004	0.008	0.012
L1	0.35	0.54	0.69	0.014	0.021	0.029
HE	2.10	2.40	2.64	0.083	0.094	0.104
θ	0°		10°	0°		10°

#### STYLE 6:

- PIN 1. BASE
  - **EMITTER**
  - COLLECTOR

#### **SOLDERING FOOTPRINT**



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